HMC407MS8G / 407MS8GE

v04.1019

GaAs InGaP HBT MMIC POWER AMPLIFIER, 5 - 7 GHz

Typical Applications

This amplifier is ideal for use as a power amplifier for 5 - 7 GHz applications:

- UNII
- HiperLAN

Features

Gain: 15 dB

Saturated Power: +29 dBm

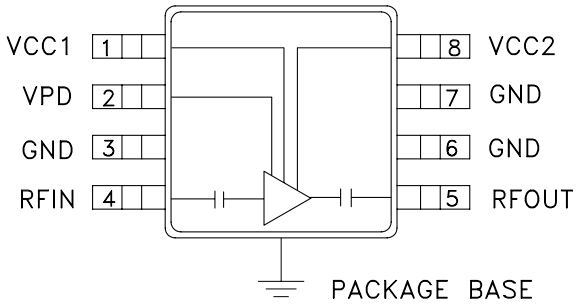
28% PAE

Supply Voltage: +5V

Power Down Capability

No External Matching Required

Functional Diagram



General Description

The HMC407MS8G & HMC407MS8GE are high efficiency GaAs InGaP Heterojunction Bipolar Transistor (HBT) MMIC Power amplifiers which operate between 5 and 7 GHz. The amplifier requires no external matching to achieve operation and is thus truly 50 Ohm matched at input and output. The amplifier is packaged in a low cost, surface mount 8 leaded package with an exposed base for improved RF and thermal performance. The amplifier provides 15 dB of gain, +29 dBm of saturated power at 28% PAE from a +5V supply voltage. Power down capability is available to conserve current consumption when the amplifier is not in use.

Electrical Specifications, T_A = +25° C, Vs = 5V, Vpd = 5V

Parameter		Min.	Typ.	Max.	Min.	Typ.	Max.	Units
Frequency Range			5 - 7			5.6 - 6.0		GHz
Gain		10	15	18	12	15	18	dB
Gain Variation Over Temperature			0.025	0.035		0.025	0.035	dB/ °C
Input Return Loss			12			12		dB
Output Return Loss			15			15		dB
Output Power for 1 dB Compression (P1dB)		21	25		22	25		dBm
Saturated Output Power (Psat)			29			29		dBm
Output Third Order Intercept (IP3)		32	37		36	40		dBm
Noise Figure			5.5			5.5		dB
Supply Current (Icq)	Vpd = 0V/5V		0.002 / 230			0.002 / 230		mA
Control Current (Ipd)	Vpd = 5V		7			7		mA
Switching Speed	tON, tOFF		30			30		ns

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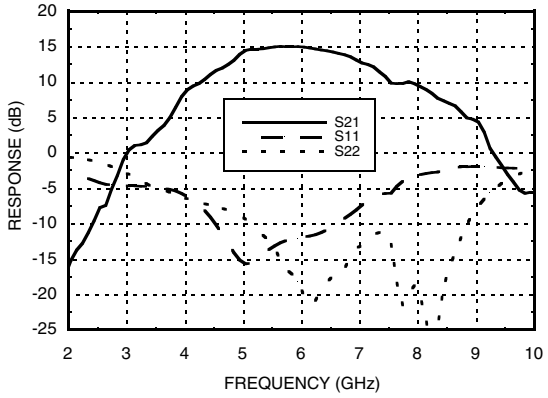
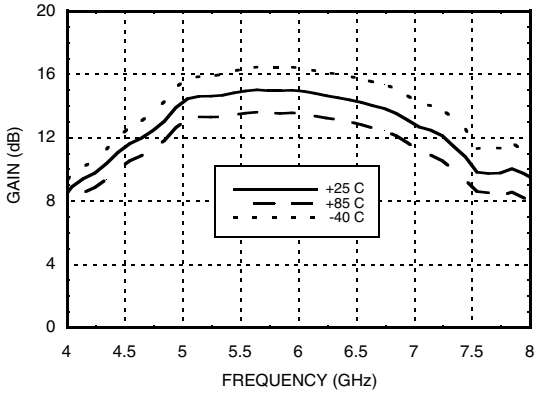
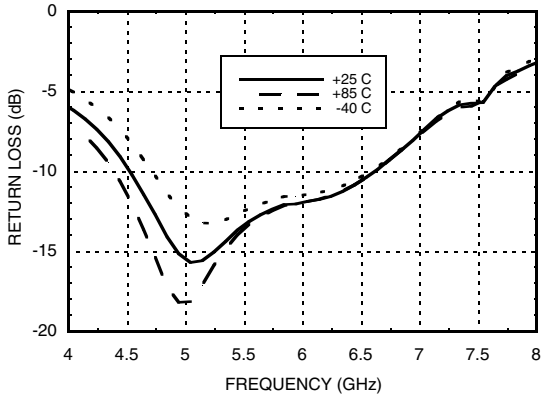
Broadband Gain & Return Loss



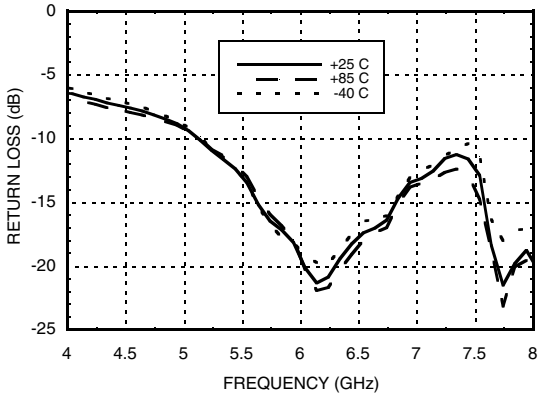
Gain vs. Temperature



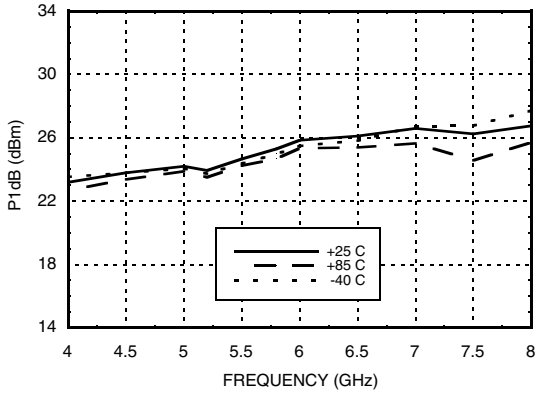
Input Return Loss vs. Temperature



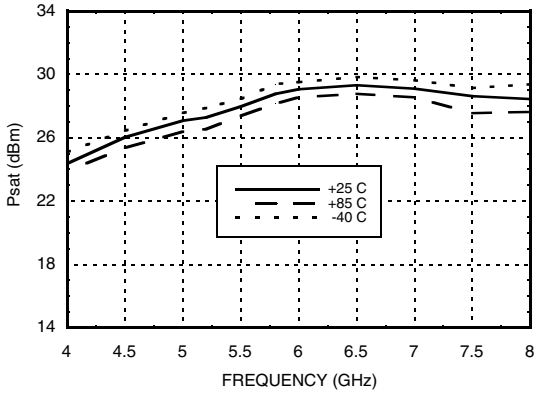
Output Return Loss vs. Temperature



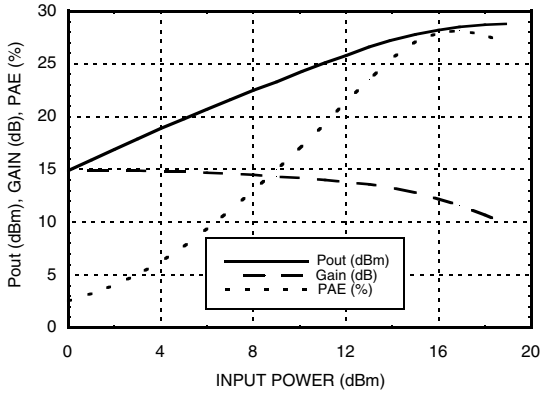
P1dB vs. Temperature



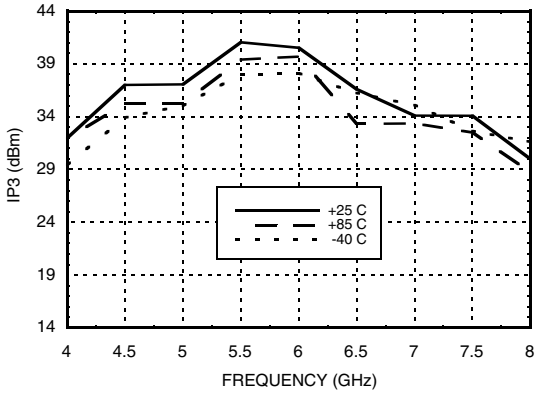
Psat vs. Temperature



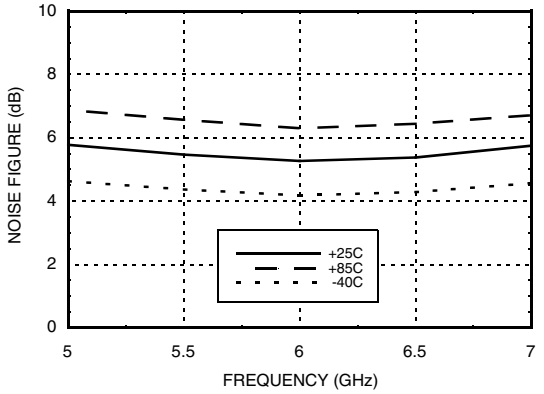
Power Compression @ 5.8 GHz



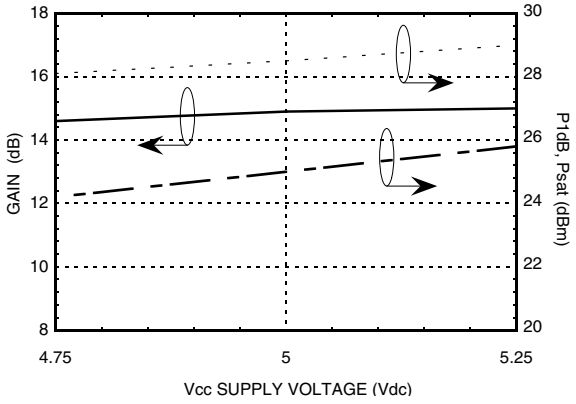
Output IP3 vs. Temperature



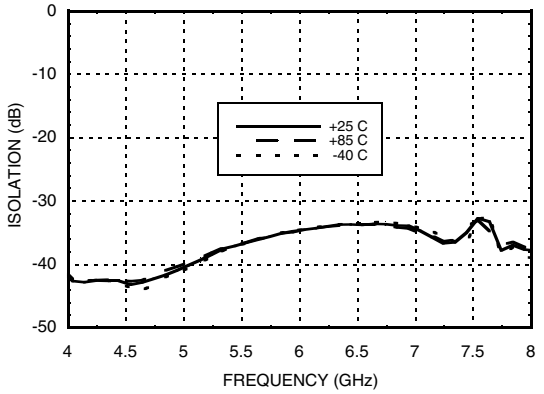
Noise Figure vs. Temperature



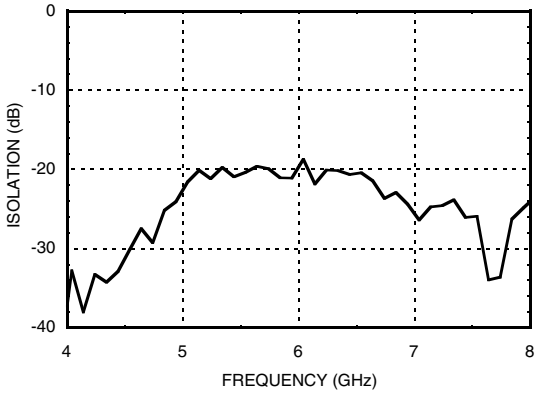
Gain & Power vs. Supply Voltage



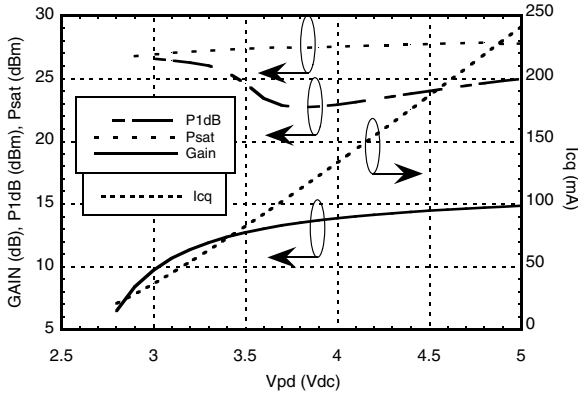
Reverse Isolation vs. Temperature



Power Down Isolation



Gain, Power & Quiescent Supply Current vs. Vpd @ 5.8 GHz

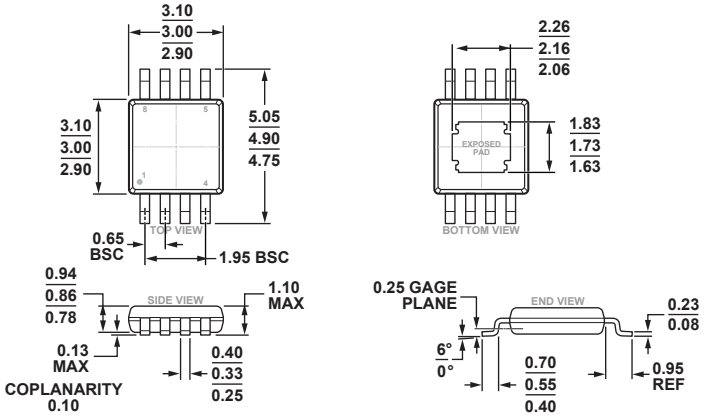


Absolute Maximum Ratings

Collector Bias Voltage (Vcc1, Vcc2)	+5.5 Vdc
Control Voltage (Vpd)	+5.5 Vdc
RF Input Power (RFIN)(Vs = Vpd = +5Vdc)	+20 dBm
Junction Temperature	150 °C
Continuous Pdiss (T = 85 °C) (derate 31 mW/°C above 85 °C)	2 W
Thermal Resistance (junction to ground paddle)	32 °C/W
Storage Temperature	-65 to +150 °C
Operating Temperature	-40 to +85 °C

ELECTROSTATIC SENSITIVE DEVICE
OBSERVE HANDLING PRECAUTIONS

Outline Drawing



COMPLIANT TO JEDEC STANDARDS MO-187-AA-T

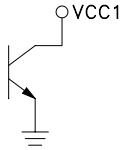
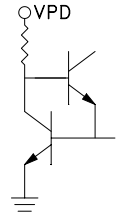
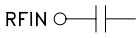
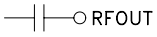
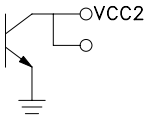
8-Lead Mini Small Outline Package with Exposed Pad [MINI_SO_EP]
(RH-8-1)
Dimensions shown in millimeters

Package Information

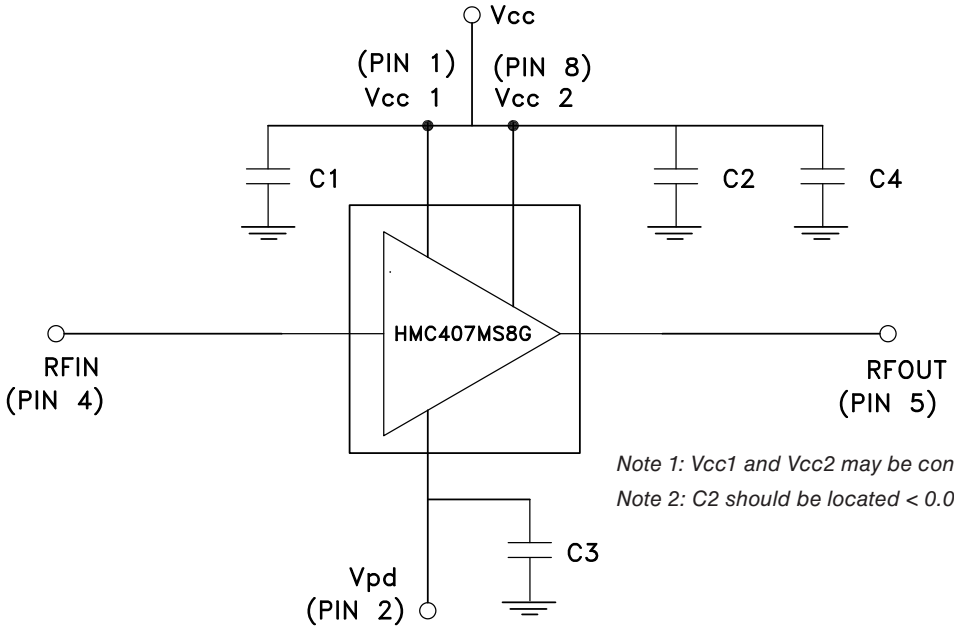
Part Number	Package Body Material	Lead Finish	MSL Rating	Package Marking [3]
HMC407MS8G	Low Stress Injection Molded Plastic	Sn/Pb Solder	MSL1 [1]	H407 XXXX
HMC407MS8GE	RoHS-compliant Low Stress Injection Molded Plastic	100% matte Sn	MSL1 [2]	H407 XXXX
HMC407MS8GETR	RoHS-compliant Low Stress Injection Molded Plastic	100% matte Sn	MSL1 [2]	H407 XXXX
HMC407MS8GTR	Low Stress Injection Molded Plastic	Sn/Pb Solder	MSL1 [1]	H407 XXXX
104987-HMC407MS8G	Eval Board			

[1] Max peak reflow temperature of 235 °C
[2] Max peak reflow temperature of 260 °C
[3] 4-Digit lot number XXXX

Pin Descriptions

Pin Number	Function	Description	Interface Schematic
1	Vcc1	Power supply voltage for the first amplifier stage. An external bypass capacitor of 330 pF is required as shown in the application schematic.	
2	Vpd	Power control pin. For maximum power, this pin should be connected to 5V. A higher voltage is not recommended. For lower die current, this voltage can be reduced.	
3, 6, 7	GND	Ground: Backside of package has exposed metal ground slug that must be connected to ground thru a short path. Vias under the device are required.	
4	RFIN	This pin is AC coupled and matched to 50 Ohms.	
5	RFOUT	This pin is AC coupled and matched to 50 Ohms.	
8	Vcc2	Power supply voltage for the output amplifier stage. An external bypass capacitor of 330 pF is required. This capacitor should be placed no more than 20 mils form package lead.	

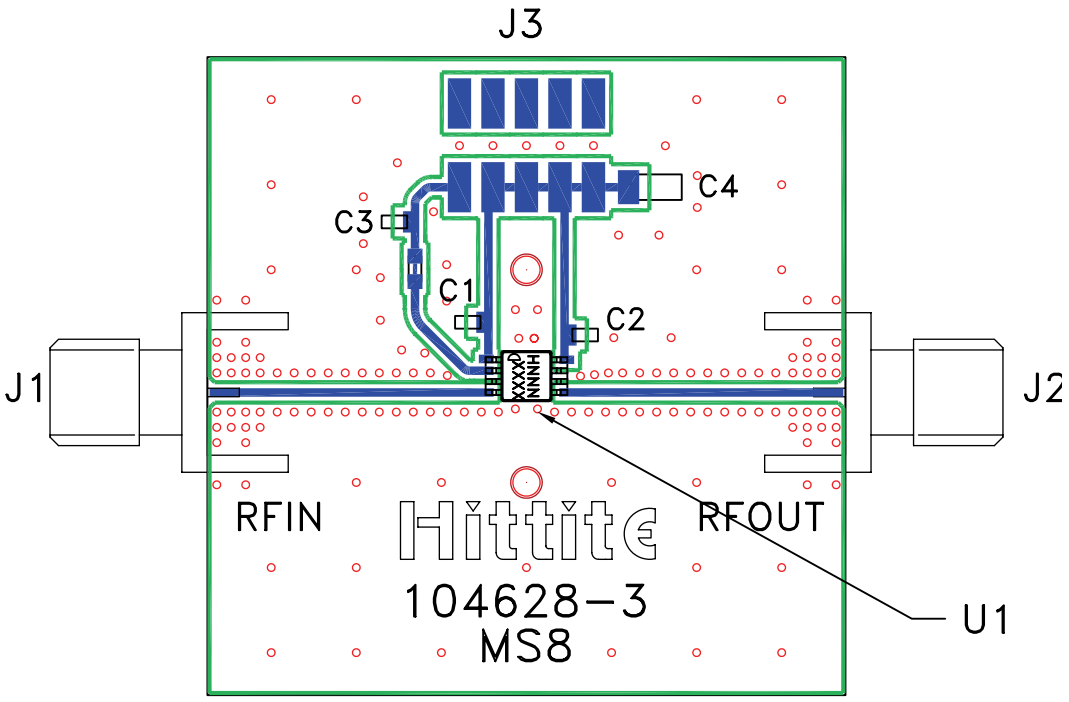
Application Circuit



Note 1: Vcc1 and Vcc2 may be connected to a common Vcc.

Note 2: C2 should be located < 0.020" from Pin 8 (Vcc2).

Evaluation PCB



List of Materials for Evaluation PCB 104987 [1]

Item	Description
J1 - J2	PCB Mount SMA RF Connector
J3	2 mm DC Header
C1 - C3	330 pF Capacitor, 0603 Pkg.
C4	2.2 µF Capacitor, Tantalum
U1	HMC407MS8G / HMC407MS8GE Amplifier
PCB [2]	104628 Eval Board

[1] Reference this number when ordering complete evaluation PCB

[2] Circuit Board Material: Roger 4350

The circuit board used in the final application should use RF circuit design techniques. Signal lines should have 50 Ohm impedance while the package ground leads and exposed paddle should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation board should be mounted to an appropriate heat sink. The evaluation circuit board shown is available from Analog Devices, upon request.

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